

	Type	Hits	Search Text	DBs
1	IS&R	3586	(257/344,369,371,377,382,383,384,408,412,413,900).CCLS.	USPAT; USOCR
2	IS&R	3765	(438/184,199,230,265,300,303,585,587,588,592,595).CCLS.	USPAT; USOCR
3	BRS	1322	((257/344,369,371,377,382,383,384,408,412,413,900).CCLS.) and (thin and thick)	USPAT
4	BRS	1371	((438/184,199,230,265,300,303,585,587,588,592,595).CCLS.) and (thin and thick)	USPAT
5	IS&R	2605	(257/344,369,371,377,382,383,384,408,412,413,900).CCLS.	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB
6	BRS	235	((257/344,369,371,377,382,383,384,408,412,413,900).CCLS.) and (thin and thick)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	IS&R	1029	(438/184,199,230,265,300,303,585,587,588,592,595).CCLS.	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB
8	BRS	231	((438/184,199,230,265,300,303,585,587,588,592,595).CCLS.) and (thin and thick)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
9	BRS	1361	(spacer spacers) with (thin and thick)	USPAT
10	BRS	928	((spacer spacers) with (thin and thick)) and substrate	USPAT
11	BRS	201	(((spacer spacers) with (thin and thick)) and substrate) and CMOS	USPAT
12	BRS	11638	((long longer) and (short shorter)) with (gate gates transistor transistors)	USPAT
13	BRS	3025	((long longer) with (short shorter)) with (gate gates transistor transistors)	USPAT
14	BRS	10	((long longer) with (short shorter)) with (gate gates transistor transistors) with (silicide silicides)	USPAT
15	BRS	84	(((long longer) and (short shorter)) with (silicide silicides)) and (gate gates transistor transistors)	USPAT

	Type	Hits	Search Text	DBs
16	BRS	95	((long longer) and (short shorter)) with (silicide silicides))	USPAT
17	BRS	11	S5 not S4	USPAT
18	BRS	329	((large larger) and (small smaller)) with (silicide silicides)) and (gate gates transistor transistors)	USPAT
19	BRS	100	((large larger) and (small smaller)) with (silicide silicides)) and (gate gates transistor transistors)	US-PGPUB
20	BRS	1359	((257/344,369,371,377,382,383,384,408,412,413,900).CCLS.) and (thin and thick)	USPAT
21	BRS	1448	((438/184,199,230,265,300,303,585,587,588,592,595).CCLS.) and (thin and thick)	USPAT
22	BRS	256	((257/344,369,371,377,382,383,384,408,412,413,900).CCLS.) and (thin and thick)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
23	BRS	274	((438/184,199,230,265,300,303,585,587,588,592,595).CCLS.) and (thin and thick)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
24	BRS	215	((spacer spacers) with (thin and thick)) and substrate) and CMOS	USPAT
25	BRS	11	((long longer) with (short shorter)) with (gate gates transistor transistors) with (silicide silicides)	USPAT
26	BRS	86	((long longer) and (short shorter)) with (silicide silicides)) and (gate gates transistor transistors)	USPAT
27	BRS	348	((large larger) and (small smaller)) with (silicide silicides)) and (gate gates transistor transistors)	USPAT
28	BRS	112	((large larger) and (small smaller)) with (silicide silicides)) and (gate gates transistor transistors)	US-PGPUB
29	BRS	1394	((257/344,369,371,377,382,383,384,408,412,413,900).CCLS.) and (thin and thick)	USPAT

	Type	Hits	Search Text	DBs
30	BRS	1495	((438/184,199,230,265,300,303,585,587,588,592,595).CCLS.) and (thin and thick)	USPAT
31	BRS	277	((257/344,369,371,377,382,383,384,408,412,413,900).CCLS.) and (thin and thick)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
32	BRS	302	((438/184,199,230,265,300,303,585,587,588,592,595).CCLS.) and (thin and thick)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
33	BRS	217	(((spacer spacers) with (thin and thick)) and substrate) and CMOS	USPAT
34	BRS	11	((long longer) with (short shorter)) with (gate gates transistor transistors) with (silicide silicides)	USPAT
35	BRS	87	(((long longer) and (short shorter)) with (silicide silicides)) and (gate gates transistor transistors)	USPAT
36	BRS	353	(((large larger) and (small smaller)) with (silicide silicides)) and (gate gates transistor transistors)	USPAT
37	BRS	126	(((large larger) and (small smaller)) with (silicide silicides)) and (gate gates transistor transistors)	US-PGPUB
38	IS&R	1	(("5963803") or ("2001002648")).PN.	US-PGPUB; USPAT
39	IS&R	2	(("5963803") or ("20010052648")).PN.	US-PGPUB; USPAT